NSN 5962-01-347-7482

Memory Microcircuit - Page 1 of 1





Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Burn in and electrostatic sensitive and programmed

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Criticality Code Justification:

Feat

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, altered, programmed prom

Memory Device Type:

Prom

Special Features:

Nuclear hardness critical item

Terminal Type And Quantity:

32 leadless

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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